## NSN 5961-01-310-5430

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.230 inches and 0.300 inches
Terminal Length:
Between 1.000 inches and 1.500 inches
Overall Diameter:
Between 0.085 inches and 0.130 inches
Function For Which Designed:
Voltage regulator
End Application:
1440-01-215-4868 armament subsystem, helicopter, guided missile
Mounting Method:
Terminal
Features Provided:
Quality assurance level tx
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
16.0 regulator voltage and 12.2 reverse voltage, instantaneous
Voltage Tolerance In Percent:
-5.0/+5.0
Current Rating Per Characteristic:
5.00 microamperes collector current, dc peak and 24.00 milliamperes emitter current, dc
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/435 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

**Fiig:** A110a0

No